

UNISONIC TECHNOLOGIES CO., LTD

UF40N07

Preliminary

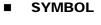
40A, 70V N-CHANNEL POWER MOSFET

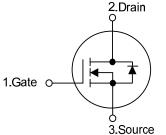
DESCRIPTION

The UTC **UF40N07** is a high voltage power MOSFET and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and have a high rugged avalanche characteristics. This power MOSFET is usually used at high speed switching applications in power supplies, PWM motor controls, high efficient DC to DC converters and bridge circuits.



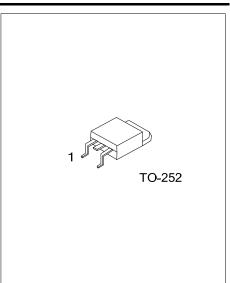
- * $R_{DS(ON)}$ < 25 m Ω @ V_{GS} =10V, I_D =20A
- * High switching speed
- * 100% avalanche tested





ORDERING INFORMATION





ABSOLUTE MAXIMUM RATINGS (T_A =25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V _{DSS}	70	V
Gate-Source Voltage		V _{GSS}	±25	V
Continuous Drain Current	Continuous	I _D	40	А
	Pulsed	I _{DM}	160	А
Avalanche Energy		E _{AS}	200	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	18	V/ns
Power Dissipation		PD	1	mW
Junction Temperature		TJ	+150	°C
Storage Temperature Range		T _{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 3. L=0.8mH, I_{AS} =22.3A, V_{DD} =50V, R_G =25 Ω , Starting T_J = 25°C
- 4. $I_{SD} \leq 30A$, di/dt $\leq 200A/\mu s$, $V_{DD} \leq BV_{DSS}$, Starting $T_J = 25^{\circ}C$

THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ _{JA}	110	°C/W
Junction to Case	θις	1.95	°C/W

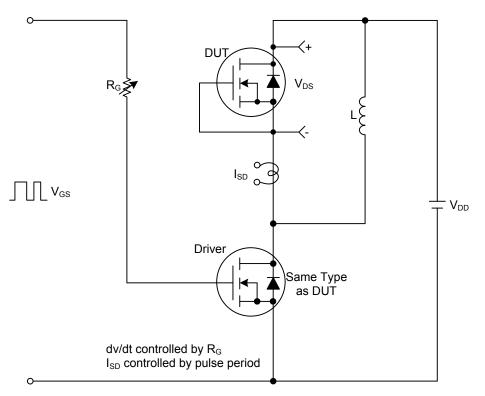
ELECTRICAL CHARACTERISTICS (T_A =25°C, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
OFF CHARACTERISTICS				•	•	•		
Drain-Source Breakdown Voltage		BV _{DSS}	I _D =250μA, V _{GS} =0V	70			V	
Drain-Source Leakage Current		I _{DSS}	V _{DS} =70V, V _{GS} =0V			1	μA	
Gate-Source Leakage Current	Forward	- I _{GSS}	V _{GS} =+20V, V _{DS} =0V			10	μA	
	Reverse		V _{GS} =-20V, V _{DS} =0V			-10	μA	
ON CHARACTERISTICS								
Gate Threshold Voltage		V _{GS(TH)}	$I_D=250\mu A, V_{DS}=V_{GS}$	2.0		4.0	V	
Static Drain-Source On-State Resistance		R _{DS(ON)}	V _{GS} =10V, I _D =20A			25	mΩ	
DYNAMIC PARAMETERS						-	-	
Input Capacitance		C _{ISS}	V _{GS} =0V, V _{DS} =25V, f=1MHz		1613		рF	
Output Capacitance		C _{OSS}			306		рF	
Reverse Transfer Capacitance		C _{RSS}			36		рF	
SWITCHING PARAMETERS						-	-	
Total Gate Charge (Note 1)		Q _G	V _{GS} =50V, V _{DS} =50V, I _D =1.3A -I _G =100μA (Note 1, 2)		116		nC	
Gate to Source Charge		Q _{GS}			9		nC	
Gate to Drain Charge		Q _{GD}			14		nC	
Turn-ON Delay Time (Note 1)		t _{D(ON)}	V _{GS} =30V, V _{DD} =30V, R _G =25Ω, I _D =0.5A (Note 1, 2)		70		ns	
Rise Time		t _R			72		ns	
Turn-OFF Delay Time		t _{D(OFF)}			360		ns	
Fall-Time		t⊨			100		ns	
SOURCE- DRAIN DIODE RATINGS	S AND CHA	RACTERIST	ICS 🤇			-	-	
Maximum Body-Diode Continuous Current		Is				40	Α	
Maximum Body-Diode Pulsed Current		I _{SM}	TRE OT	1		160	Α	
Drain-Source Diode Forward Voltage (Note 1)		V _{SD}	I _S =40A, V _{GS} =0V			1.4	V	
Body Diode Reverse Recovery Time (Note 1)		trr	I _S =40A, V _{GS} =0V		66		ns	
Body Diode Reverse Recovery Charge		Q _{rr}	dl _F /dt = 100A/µs		0.16		μC	
Notes: 1. Pulse Test: Pulse width \leq 300µs, Duty cycle \leq 2%.								
2. Essentially independent of	operating te	emperature.	1.1.1					

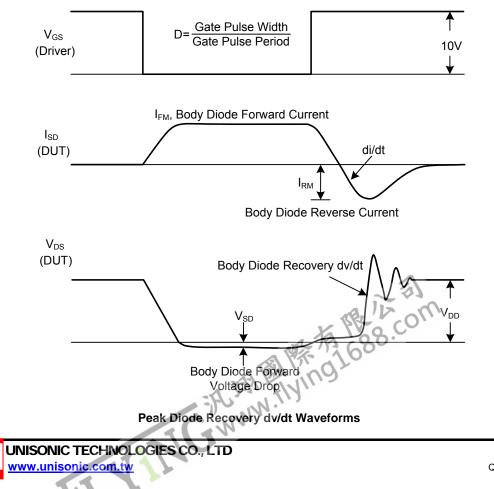
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■ TEST CIRCUITS AND WAVEFORMS

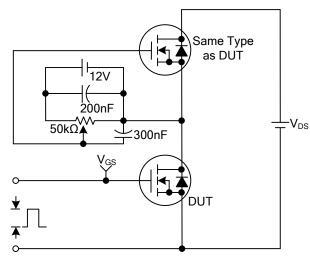


Peak Diode Recovery dv/dt Test Circuit

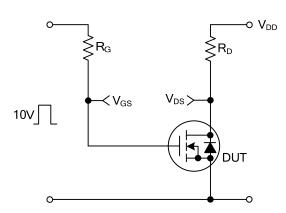


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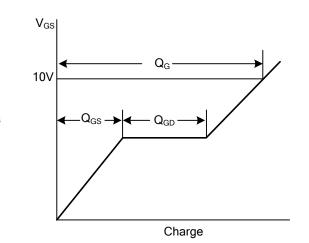


Gate Charge Test Circuit

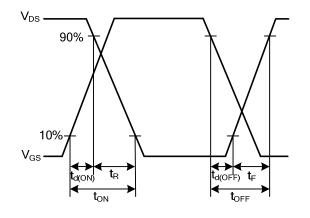


Resistive Switching Test Circuit

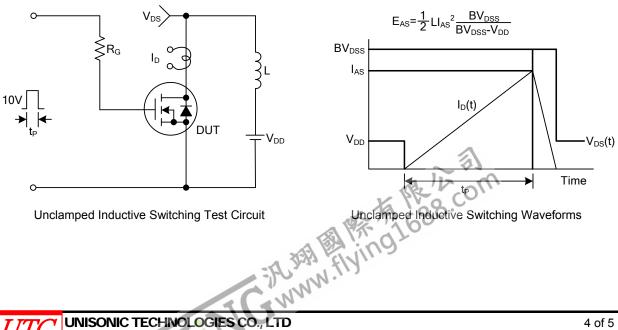
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Gate Charge Waveforms



Resistive Switching Waveforms



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